

#### ■ PRODUCT CHARACTERISTICS

VR(@IC=0.5mA)	100V
VF(Typ@IF=15A)	0.82V
IR(@VR=100V)	50uA
ID	30A

### ■ MECHANICAL CHARACTERISTICS

- \* Case: Epoxy, Molded
- \* Finish: All External Surfaces Corrosion Resistant and Terminal
- \* Leads are Readily Solderable
- \* Lead Temperature for Soldering Purposes: 260 °C Max. for 10 Seconds

### ■ FEATURES

- \* Guard Ring for Stress Protection
- \* Low Forward Voltage
- \* Low Power Loss/High Efficiency
- \* High Surge Capacity
- \* Low Stored Charge Majority Carrier Conduction
- \* Pb Free Packages are Available\*

# Symbol







### ■ ORDER INFORMATION

Order codes		Package	Package Packing	
Halogen-Free	Halogen	rackage	Facking	
N/A	MOT30100C	TO-251	70 pieces/Tube	
N/A	MOT30100D	TO-252	2500 pieces/reel	

### ■ MAIMUM RATINGS(Each diode leg)

Parameter		Symol	Value	Unit
Peak Repetitive Reverse Voltage		$V_{\sf RRM}$	100	V
Average Rectified Output Current	(Total)	_	30	Α
	(per Leg)	I <sub>O</sub>	15	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Reate Load		I <sub>FSM</sub>	300	Α
Operationg and Storage Temperature Range		$T_J, T_STG$	-55 to + 175	°C

## ■ ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Test Conditions	Min	Тур.	Max	Unit
Peak Repetitive Reverse Voltage	B <sub>v</sub>	I <sub>0</sub> =0.5mA T <sub>J</sub> =25°C	_	108	-	V
Forward Voltage Drop	$V_{\scriptscriptstyle F}$	I <sub>F</sub> =15AŢ <sub>J</sub> =25°C	_	0.82	0.85	V
Leakage Current	I <sub>R</sub>	V <sub>R</sub> =100V, T <sub>J</sub> =25°C		1	0.05	mA
		V <sub>R</sub> =100V, T <sub>J</sub> =125°C	_	_	6	

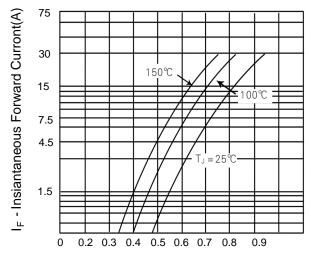


Figure 1. Typical Forward Voltage Per Diode

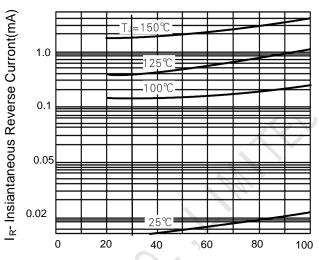
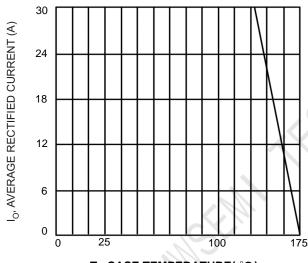
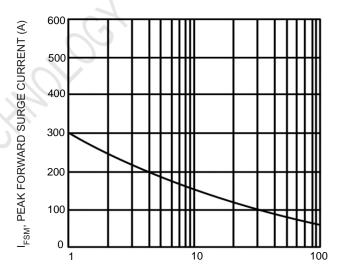


Figure 2. Typical Reverse Current Per Diode



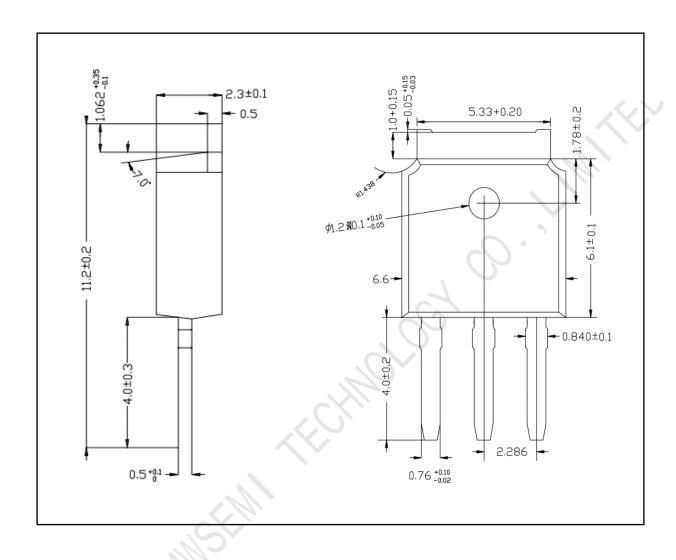
T<sub>C</sub>,CASE TEMPERATURE( °C)
Fig.3 Forward Current Derating Curve



NUMBER OF CYCLES AT 60HZ Fig.4 Max Non-Repetitive Surge Current

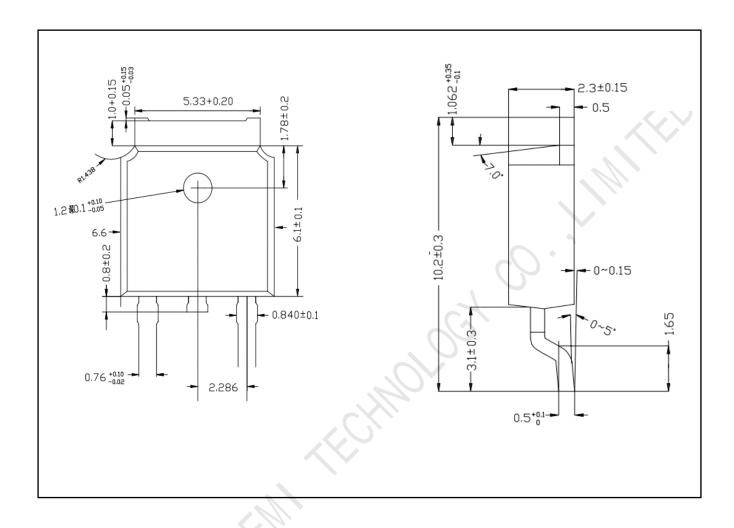


### ■ TO-251-3L PACKAGE OUTLINE DIMENSIONS





### ■ TO-252-2L PACKAGE OUTLINE DIMENSIONS





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